

L Number	Hits	Search Text	DB	Time stamp
-	0	thyristor with (momentary near3 switch) with (transistor fet mosfet jfet bjt npn pnp scr)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 14:08
-	0	thyristor same (momentary near3 switch) same (transistor fet mosfet jfet bjt npn pnp scr)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 14:08
-	1	thyristor with (momentary near3 switch) with (transistor fet mosfet jfet bjt npn pnp scr)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 14:08
-	11	thyristor same (momentary near3 switch) same (transistor fet mosfet jfet bjt npn pnp scr)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 15:50
-	337	(momentary near3 switch) with (transistor fet mosfet jfet bjt npn pnp scr)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 14:20
-	167	(momentary near3 switch) with (transistor fet mosfet jfet bjt npn pnp scr) and (power near3 (supply surce))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 15:23
-	4	713/320.ccls. and (momentary near2 switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 15:25
-	0	713/30.ccls. and (momentary near2 switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 15:25
-	16	713/300.ccls. and (momentary near2 switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 15:27
-	23	"4689492" "4538074" "5886426"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 15:45
-	173	scr same (momentary near3 switch) same (transistor fet mosfet jfet bjt npn pnp scr)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 15:51
-	367	(battery near4 drain) with (scr thyristor transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 17:34

-	0	(battery near4 drain) with (scr thyristor transistor) with (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 17:34
-	0	(battery near4 drain) with (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 17:59
-	2	(battery near4 drain) same (scr thyristor transistor) same (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 17:35
-	54	(battery) same (scr thyristor transistor) same (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 17:36
-	0	"9168236"	JPO	2004/10/20 17:54
-	1	"09168236"	JPO	2004/10/20 17:56
-	4	(battery near4 drain) same (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 18:00
-	365	(battery) same (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 18:00
-	19	(battery) same (momentary adj switch) same (computer PC laptop phone)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/20 18:01
-	17	327/538.ccls. and (SCR thyristor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:54
-	0	327/538.ccls. and (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:54
-	0	327/539.ccls. and (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:54
-	0	327/540.ccls. and (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:54
-	0	327/541.ccls. and (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:54

-	0	327/542.ccls. and (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:54
-	0	327/539.ccls. and (SCR thyristor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:54
-	10	327/540.ccls. and (SCR thyristor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 12:26
-	0	323/311.ccls. and (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 12:26
-	158	pulse near4 generation near4 (SCR thyristor fet bjt jfet mosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:34
-	2578	(gated gating) near4 (SCR thyristor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:32
-	3	(gated gating) near4 (SCR thyristor) same (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:34
-	11044	pulse near4 (SCR thyristor fet bjt jfet mosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:34
-	2562	pulse near4 (SCR thyristor fet bjt jfet mosfet) same (momerntary switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:35
-	0	pulse near4 (SCR thyristor fet bjt jfet mosfet) same (momerntary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:35
-	0	momerntary adj switch	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:35
-	2887	momentary adj switch	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:35

-	3	pulse near4 (SCR thyristor fet bjt jfet mosfet) same (momentary adj switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:36
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